## NSN 5961-01-291-0820

Thyristor Semiconductor Device - Page 1 of 1



view Online at https://aerobasegroup.com/nsn/5961-01-291-0820
nclosure Material:
Metal
Overall Length:
15.24 millimeters
Overall Diameter:
43.18 millimeters
nternal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Го-200аb
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1400.0 repetitive peak off-state voltage and 1400.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
470.00 amperes forward current, total rms horsepower metric
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
2 tab, solder lug and 1 case
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Filg:
A110a0